TOSHIBA CMOS Didital Integrated Circuit Silicon Monolithic

TC7MET138AFK

3-to-8 Line Decoder

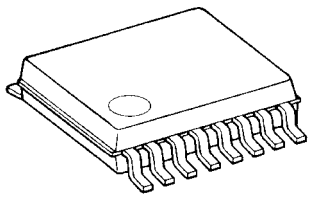
The TC7MET138AFK is an advanced high speed CMOS 3-to-8 line decoder fabricated with silicon gate C^2MOS technology. It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs ($\overline{Y}0$ - $\overline{Y}7$) will go low.

When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high. G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.



VSSOP16-P-0030-0.50

Weight: 0.02 g (typ.)

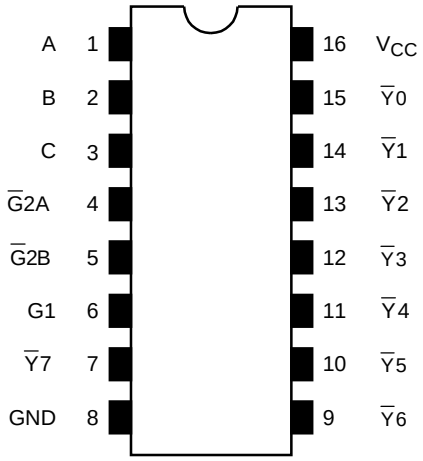
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (*) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

*: V_{CC} = 0 V

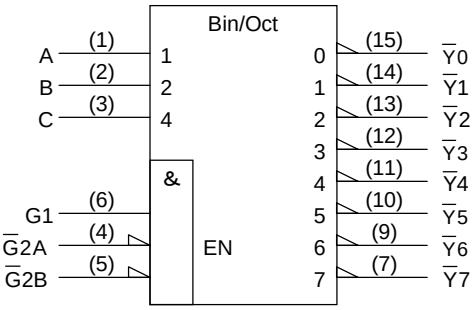
Features

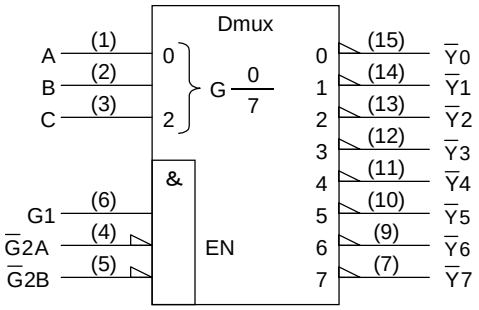
- High speed: t_{pd} = 7.6 ns (typ.) (V_{CC} = 5 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- Compatible with TTL outputs: V_{IL} = 0.8 V (max)
  V_{IH} = 2.0 V (min)
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with the 74 series (74AC/HC/ALS/LS etc.) 138 type.

Pin Assignment (top view)



IEC Logic Symbol



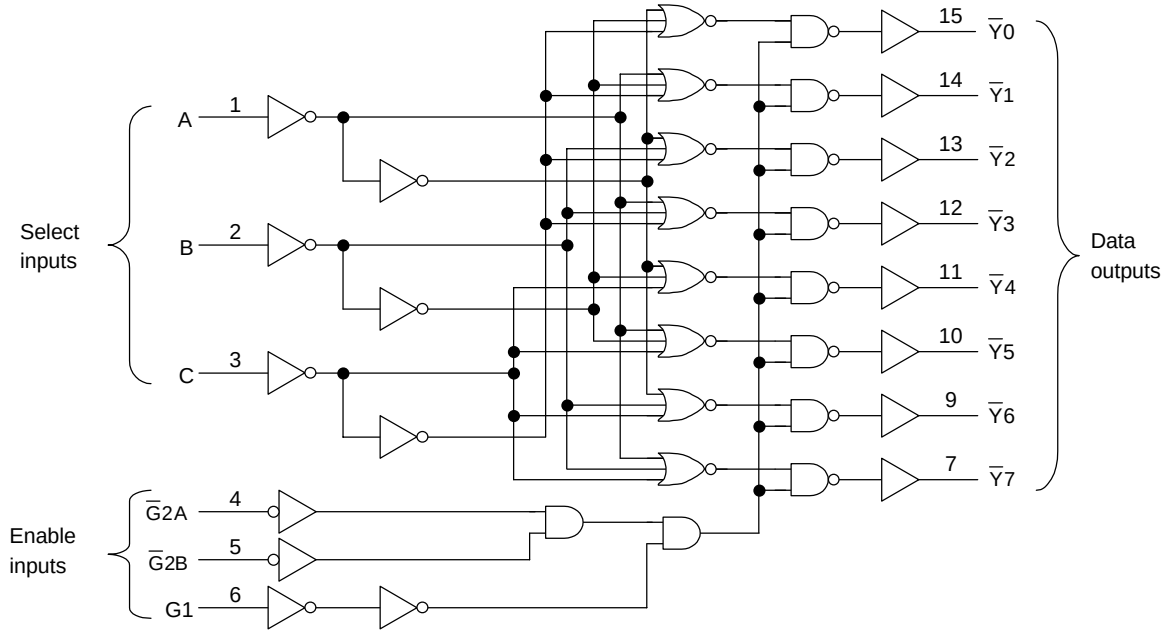


Truth Table

Inputs						Outputs								Selected Output
Enable			Select			$\overline{Y}$0	$\overline{Y}$1	$\overline{Y}$2	$\overline{Y}$3	$\overline{Y}$4	$\overline{Y}$5	$\overline{Y}$6	$\overline{Y}$7	
G1	$\overline{G}$2A	$\overline{G}$2B	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	None
X	H	X	X	X	X	H	H	H	H	H	H	H	H	None
X	X	H	X	X	X	H	H	H	H	H	H	H	H	None
H	L	L	L	L	L	L	H	H	H	H	H	H	H	$\overline{Y}$0
H	L	L	L	L	H	H	L	H	H	H	H	H	H	$\overline{Y}$1
H	L	L	L	H	L	H	H	L	H	H	H	H	H	$\overline{Y}$2
H	L	L	L	H	H	H	H	H	L	H	H	H	H	$\overline{Y}$3
H	L	L	H	L	L	H	H	H	H	L	H	H	H	$\overline{Y}$4
H	L	L	H	L	H	H	H	H	H	H	L	H	H	$\overline{Y}$5
H	L	L	H	H	L	H	H	H	H	H	H	L	H	$\overline{Y}$6
H	L	L	H	H	H	H	H	H	H	H	H	H	L	$\overline{Y}$7

X: Don’t care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~7.0 (Note1)	V
		−0.5~V_{CC} + 0.5 (Note2)	
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20 (Note3)	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65~150	°C

Note1: V_{CC} = 0 V

Note2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note3: V_{OUT} < GND, V_{OUT} > V_{CC}

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~5.5 (Note4)	V
		0~V_{CC} (Note5)	
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~20	ns/V

Note4: V_{CC} = 0 V

Note5: High or low state.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40~85°C Min	Ta = −40~85°C Max	Unit
Input voltage	High level	V_{IH}	—		4.5~5.5	2.0	—	—	2.0	—	V
	Low level	V_{IL}	—		4.5~5.5	—	—	0.8	—	0.8	
Output voltage	High level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	4.5	4.4	4.5	—	4.4	—	V
				I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
	Low level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	4.5	—	0	0.1	—	0.1	
				I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA
		I_{CCT}	Per input: V_{IN} = 3.4 V Other input: V_{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output leakage current		I_{OPD}	V_{OUT} = 5.5 V		0	—	—	0.5	—	5.0	μA

AC Characteristics (Input: $t_r = t_f = 3$ ns)

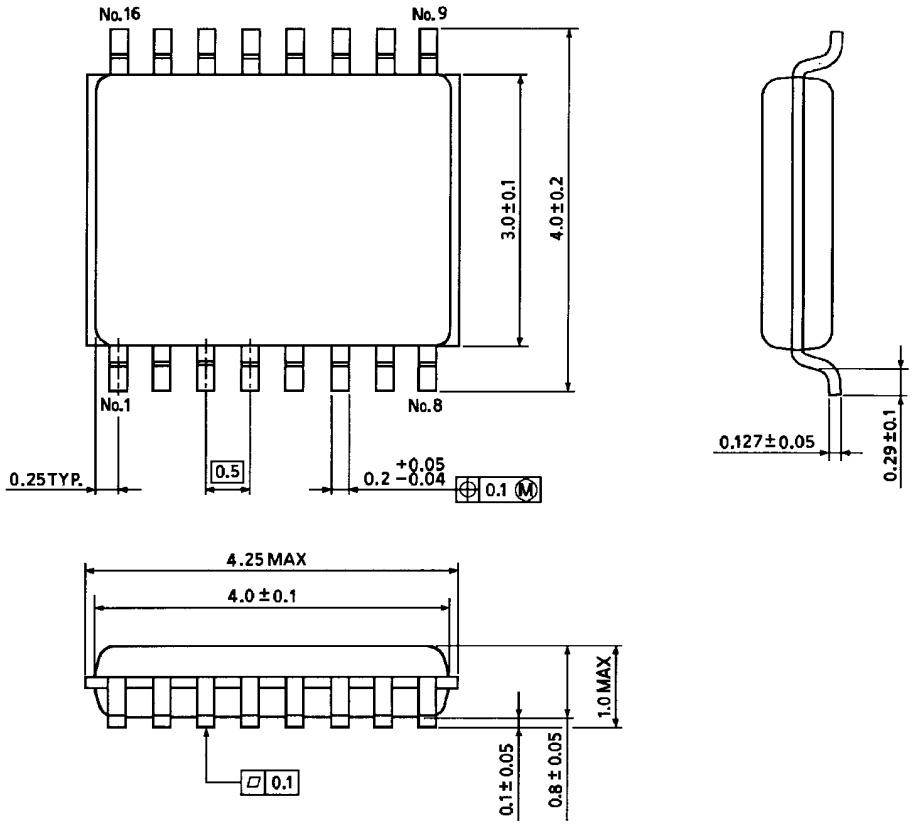
Characteristics	Symbol	Test Condition	V_{CC} (V)	C_L (pF)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40~85°C Min	Ta = −40~85°C Max	Unit
Propagation delay time (A, B, C- $\overline{Y}$)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	15	—	7.6	10.4	1.0	12.0	ns
				50	—	8.1	11.4	1.0	13.0	
Propagation delay time (G1- $\overline{Y}$)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	15	—	6.6	9.1	1.0	10.5	ns
				50	—	7.1	10.1	1.0	11.5	
Propagation delay time ($\overline{G2}$ - $\overline{Y}$)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	15	—	7.0	9.6	1.0	11.0	ns
				50	—	7.5	10.6	1.0	12.0	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note6)			—	49	—	—	—	pF

Note6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

VSSOP16-P-0030-0.50 Unit : mm



Weight: 0.02 g (typ.)

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